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2N3905 & 2N3906 Silicon PNP Transistor General Purpose TO92 Type Package

Absolute Maximum Ratings:

Collector-Emitter Voltage, V_{CEO}	40V
Collector-Base Voltage, V_{CBO}	40V
Emitter-Base Voltage, V_{EBO}	5V
Continuous Collector Current, I_C	200mA
Total Device Dissipation ($T_A = +25^\circ\text{C}$), P_D	625mW
Derate Above 25°C	5.0mW/ $^\circ\text{C}$
Total Device Dissipation ($T_A = +60^\circ\text{C}$), P_D	250mW
Total Device Dissipation ($T_C = +25^\circ\text{C}$), P_D	1.5W
Derate Above 25°C	12mW/ $^\circ\text{C}$
Operating Junction Temperature Range, T_J	-55° to +150° $^\circ\text{C}$
Storage Temperature Range, T_{stg}	-55° to +150° $^\circ\text{C}$
Thermal Resistance, Junction to Case, R_{thJC}	83.3° $^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Ambient, R_{thJA}	200° $^\circ\text{C}/\text{W}$

Electrical Characteristics: ($T_A = +25^\circ\text{C}$ unless otherwise specified)

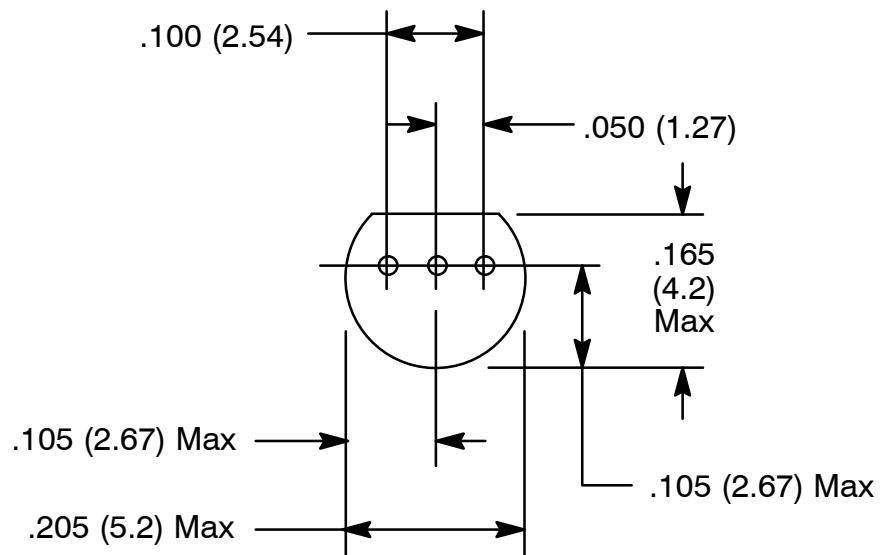
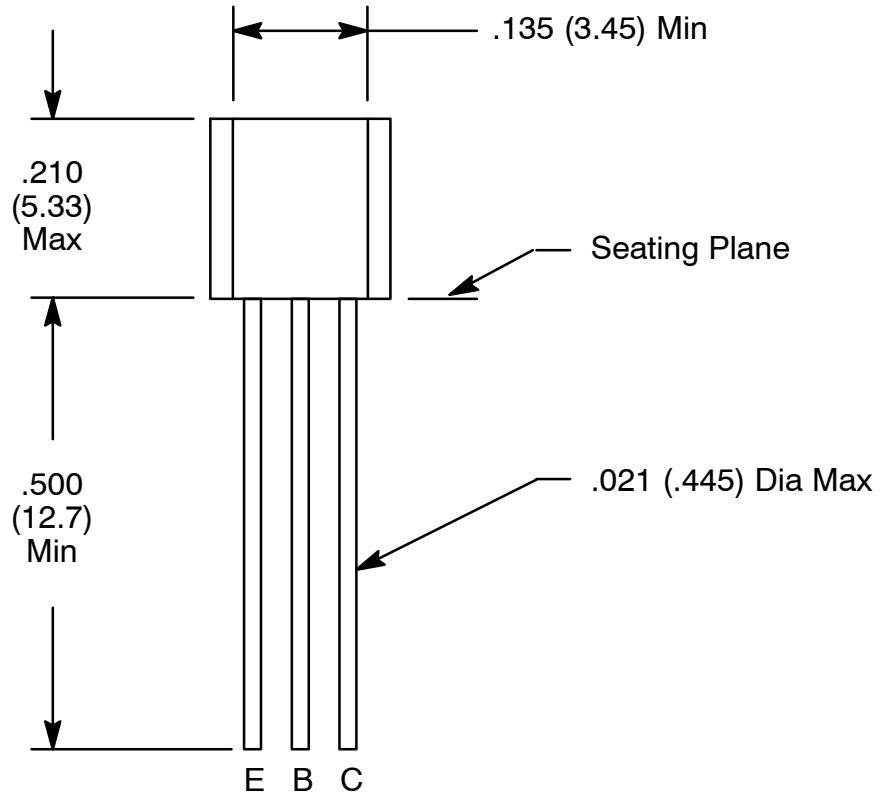
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
OFF Characteristics						
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 1\text{mA}$, $I_B = 0$, Note 1	40	-	-	V
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 10^\circ\text{A}$, $I_E = 0$	40	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 10^\circ\text{A}$, $I_C = 0$	5	-	-	V
Collector Cutoff Current	I_{CEX}	$V_{CE} = 30\text{V}$, $V_{EB} = 3\text{V}$	-	-	50	nA
Base Cutoff Current	I_{BL}	$V_{CE} = 30\text{V}$, $V_{EB} = 3\text{V}$	-	-	50	nA
ON Characteristics (Note 1)						
DC Current Gain 2N3905	h_{FE}	$V_{CE} = 1\text{V}$, $I_C = 0.1\text{mA}$	30	-	-	
2N3906			60	-	-	
2N3905		$V_{CE} = 1\text{V}$, $I_C = 1\text{mA}$	40	-	-	
2N3906			80	-	-	
2N3905		$V_{CE} = 1\text{V}$, $I_C = 10\text{mA}$	50	-	150	
2N3906			100	-	300	
2N3905		$V_{CE} = 1\text{V}$, $I_C = 50\text{mA}$	30	-	-	
2N3906			60	-	-	
2N3905		$V_{CE} = 1\text{V}$, $I_C = 100\text{mA}$	15	-	-	
2N3906			30	-	-	

Note 1. Pulse Test: Pulse Width $\leq 300^\circ\text{s}$, Duty Cycle $\leq 2\%$.

Electrical Characteristics (Cont'd): ($T_A = +25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
ON Characteristics (Cont'd) (Note 1)						
Collector-Emitter Saturation Voltage	$V_{CE(\text{sat})}$	$I_C = 10\text{mA}, I_B = 1\text{mA}$	-	-	0.25	V
		$I_C = 50\text{mA}, I_B = 5\text{mA}$	-	-	0.4	V
Base-Emitter Saturation Voltage	$V_{BE(\text{sat})}$	$I_C = 10\text{mA}, I_B = 1\text{mA}$	0.65	-	0.85	V
		$I_C = 50\text{mA}, I_B = 5\text{mA}$	-	-	0.95	V
Small-Signal Characteristics						
Current Gain-Bandwidth Product 2N3905	f_T	$I_C = 10\text{mA}, V_{CE} = 20\text{V}, f = 100\text{MHz}$	200	-	-	MHz
			250	-	-	MHz
Output Capacitance	C_{obo}	$V_{CB} = 5\text{V}, I_E = 0, f = 1\text{MHz}$	-	-	4.5	pF
Input Capacitance	C_{ibo}	$V_{CB} = 0.5\text{V}, I_C = 0, f = 100\text{kHz}$	-	-	10.0	pF
Input Impedance 2N3905	h_{ie}	$I_C = 1\text{mA}, V_{CE} = 10\text{V}, f = 1\text{kHz}$	0.5	-	8.0	k \leq
			2.0	-	12	k \leq
Voltage Feedback Ratio 2N3905	h_{re}	$I_C = 1\text{mA}, V_{CE} = 10\text{V}, f = 1\text{kHz}$	0.1	-	5.0	$\times 10^{-4}$
			0.1	-	10	$\times 10^{-4}$
Small-Signal Current Gain 2N3905	h_{fe}	$I_C = 1\text{mA}, V_{CE} = 10\text{V}, f = 1\text{kHz}$	50	-	200	
			100	-	400	
Output Admittance 2N3905	h_{oe}	$I_C = 1\text{mA}, V_{CE} = 10\text{V}, f = 1\text{kHz}$	1.0	-	40	$^\circ\text{mhos}$
			3.0	-	60	$^\circ\text{mhos}$
Noise Figure 2N3905	NF	$I_C = 100^\circ\text{A}, V_{CE} = 5\text{V}, R_S = 1\text{k}\Omega, f = 10\text{Hz to } 15.7\text{kHz}$	-	-	5.0	db
			-	-	4.0	db
Switching Characteristics						
Delay Time	t_d	$V_{CC} = 3\text{V}, V_{EB} = 0.5\text{V}, I_C = 10\text{mA}, I_{B1} = 1\text{mA}$	-	-	35	ns
Rise Time	t_r		-	-	35	ns
Storage Time 2N3905	t_s	$V_{CC} = 3\text{V}, I_C = 10\text{mA}, I_{B1} = I_{B2} = 1\text{mA}$	-	-	200	ns
			-	-	225	ns
Fall Time 2N3905	t_f		-	-	60	ns
			-	-	75	ns

Note 1. Pulse Test: Pulse Width $\leq 300^\circ\text{s}$, Duty Cycle $\leq 2\%$.



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